

6MBI75VA-060-50

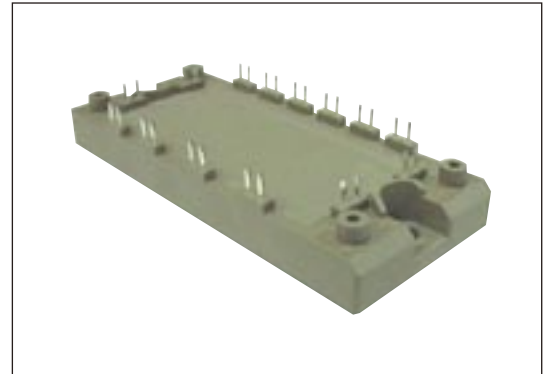
IGBT MODULE (V series) 600V / 75A / 6 in one package

■ Features

- Compact Package
- P.C.Board Mount
- Low $V_{CE(sat)}$

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	V_{CES}			600	V
	Gate-Emitter voltage	V_{GES}			± 20	V
	Collector current	I_c	Continuous	$T_c=80^\circ\text{C}$	75	A
		I_{cp}	1ms	$T_c=80^\circ\text{C}$	150	
		$-I_c$			75	
		$-I_c$ pulse	1ms		150	
Collector power dissipation	P_c	1 device		275	W	
Junction temperature	T_j			175	$^\circ\text{C}$	
Operating junction temperature (under switching conditions)	T_{jop}			150		
Case temperature	T_c			125		
Storage temperature	T_{stg}			-40 to +125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	V_{iso}	AC : 1min.		2500	VAC
Screw torque	Mounting (*3)	-	M5		3.5	N m

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

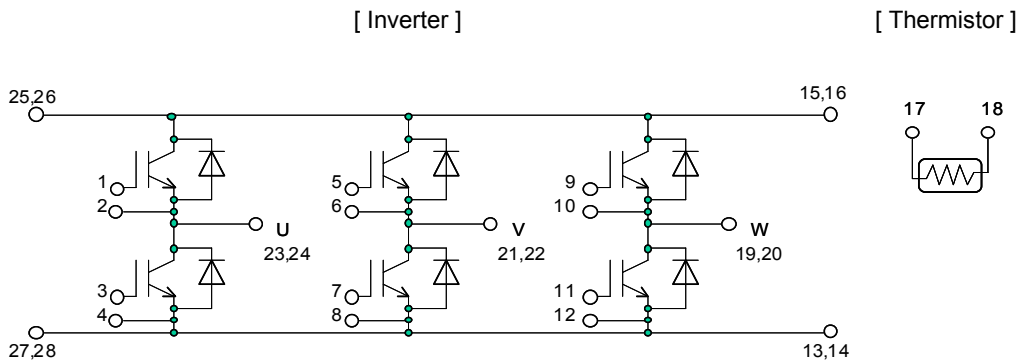
Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I_{CES}	$V_{GE} = 0V, V_{CE} = 600V$	-	-	1.0	mA	
Gate-Emitter leakage current	I_{GES}	$V_{GE} = 0V, V_{GE} = \pm 20V$	-	-	200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V, I_c = 75mA$	6.2	6.7	7.2	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_c = 75A$	Tj=25°C	-	2.00	2.45	V
			Tj=125°C	-	2.30	-	
			Tj=150°C	-	2.50	-	
	$V_{CE(sat)}$ (chip)	$V_{GE} = 15V$ $I_c = 75A$	Tj=25°C	-	1.60	2.05	
			Tj=125°C	-	1.90	-	
			Tj=150°C	-	2.10	-	
Input capacitance	C_{ies}	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$	-	4.9	-	nF	
Turn-on time	t_{on}	$V_{CC} = 300V$ $I_c = 75A$ $V_{GE} = +15 / -15V$ $R_G = 30\Omega$	-	0.39	1.20	μs	
	t_r		-	0.09	0.60		
	$t_r(i)$		-	0.03	-		
Turn-off time	t_{off}	$R_G = 30\Omega$	-	0.53	1.00	μs	
	t_f		-	0.06	0.30		
Forward on voltage	V_F (terminal)	$I_F = 75A$	Tj=25°C	-	2.00	2.45	V
			Tj=125°C	-	1.90	-	
			Tj=150°C	-	1.85	-	
	V_F (chip)	$I_F = 75A$	Tj=25°C	-	1.60	2.05	
			Tj=125°C	-	1.50	-	
			Tj=150°C	-	1.47	-	
Reverse recovery time	t_{rr}	$I_F = \pm 20$	-	-	0.35	μs	
Resistance	R	T = 25°C	-	5000	-	Ω	
		T = 100°C	465	495	520		
B value	B	T = 25 / 50°C	3305	3375	3450	K	

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.50	°C/W
		Inverter FWD	-	-	0.95	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-	

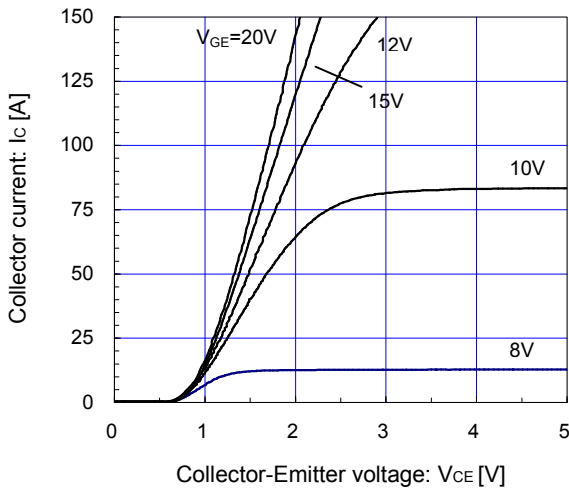
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Equivalent Circuit Schematic

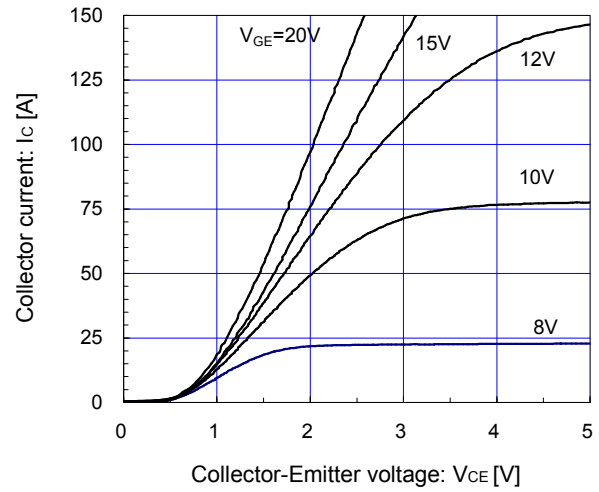


■ Characteristics (Representative)

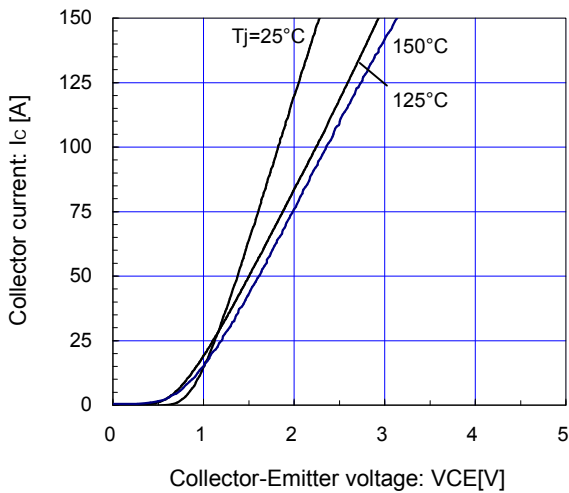
[Inverter]
 Collector current vs. Collector-Emmitter voltage (typ.)
 $T_j = 25^\circ\text{C}$ / chip



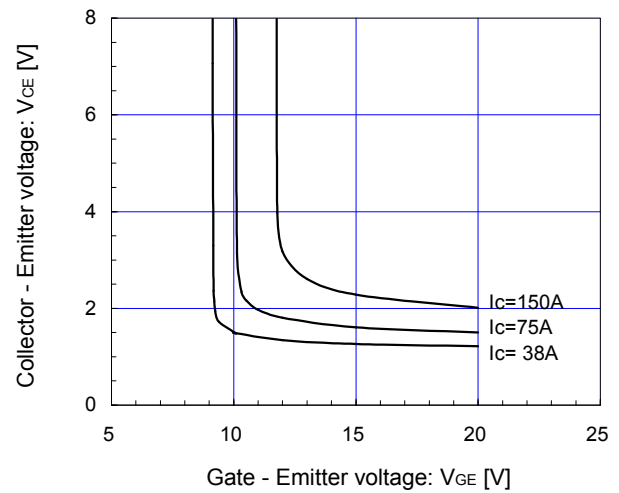
[Inverter]
 Collector current vs. Collector-Emmitter voltage (typ.)
 $T_j = 150^\circ\text{C}$ / chip



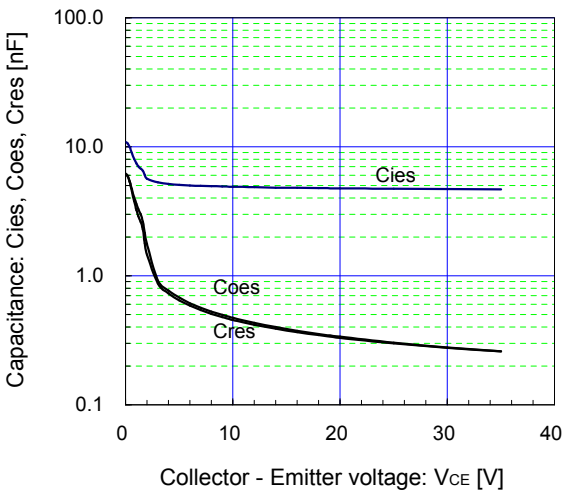
[Inverter]
 Collector current vs. Collector-Emmitter voltage (typ.)
 $V_{GE} = 15\text{V}$ / chip



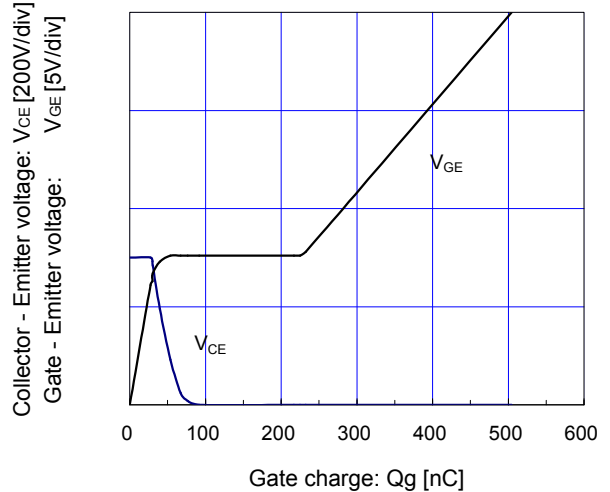
[Inverter]
 Collector-Emmitter voltage vs. Gate-Emmitter voltage (typ.)
 $T_j = 25^\circ\text{C}$ / chip

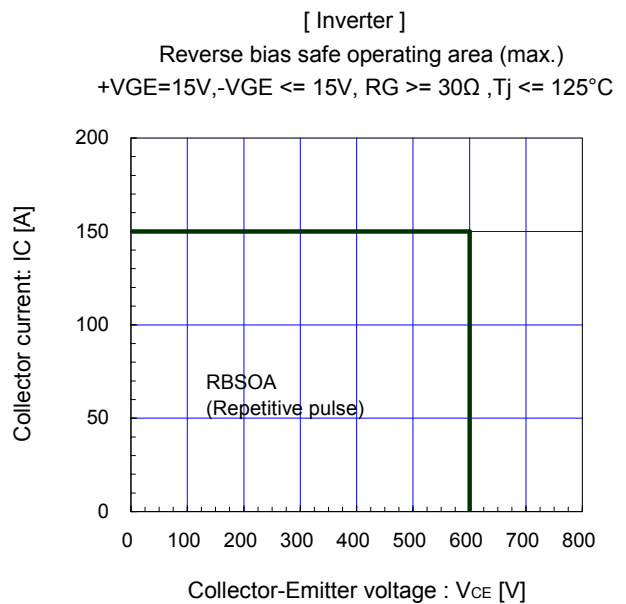
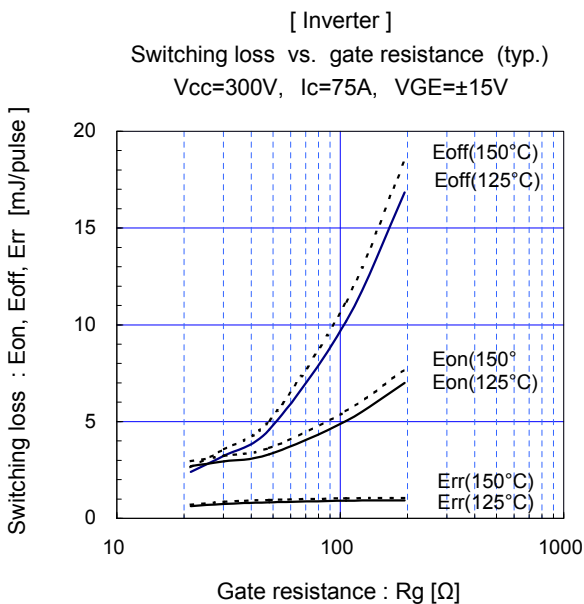
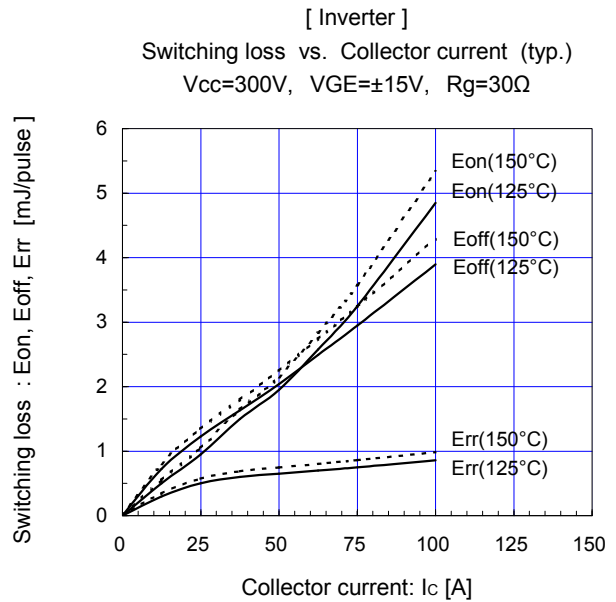
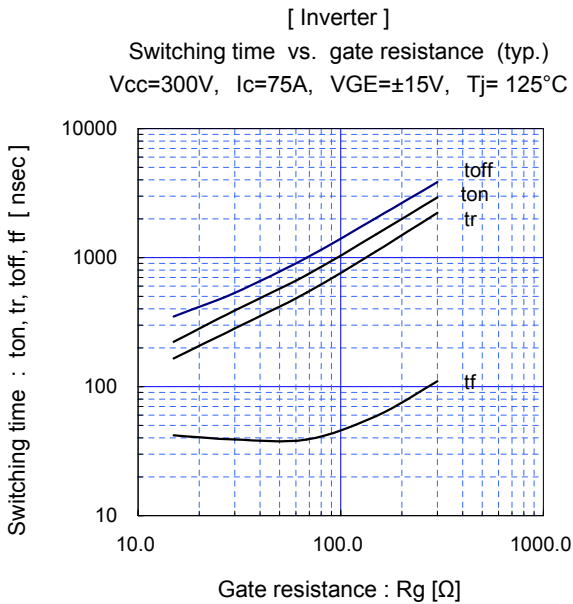
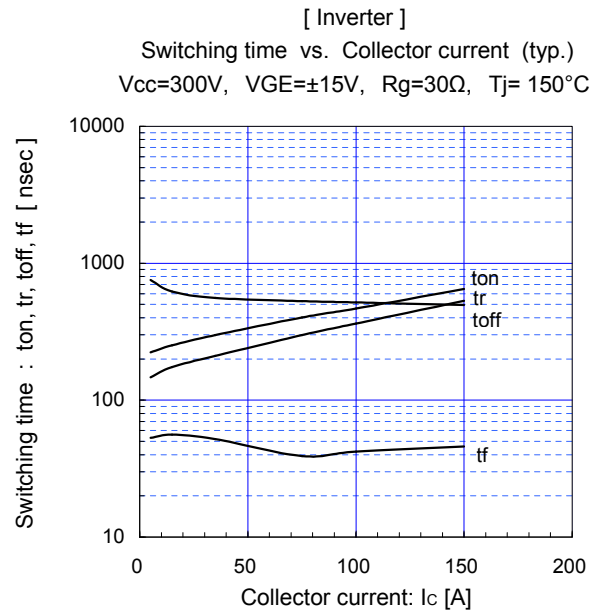
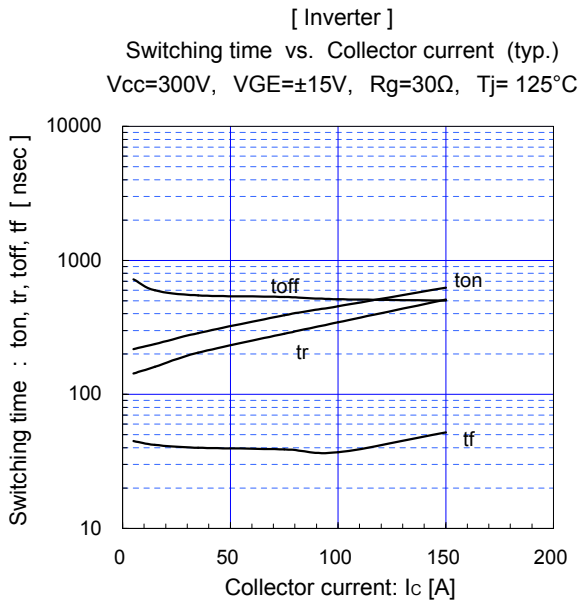


[Inverter]
 Capacitance vs. Collector-Emmitter voltage (typ.)
 $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$, $T_j = 25^\circ\text{C}$

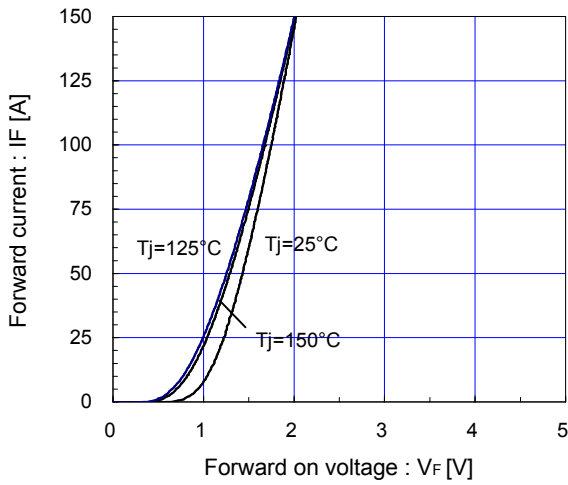


[Inverter]
 Dynamic gate charge (typ.)
 $V_{CC} = 300\text{V}$, $I_C = 75\text{A}$, $T_j = 25^\circ\text{C}$

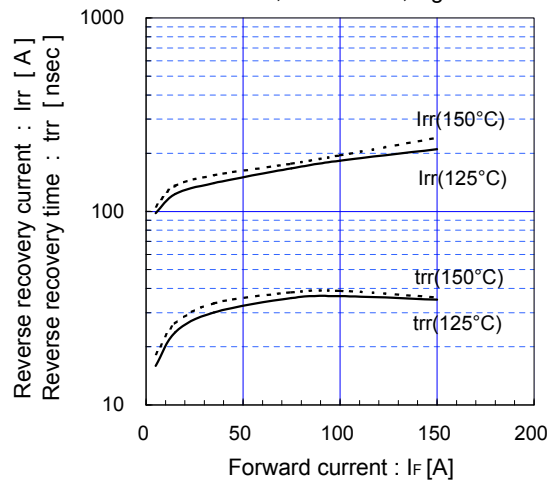




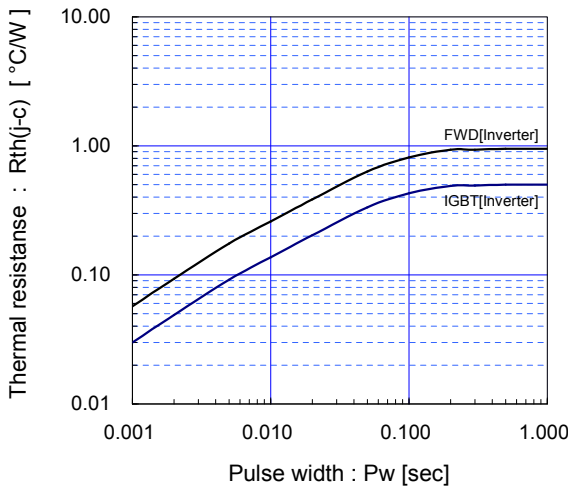
[Inverter]
Forward current vs. forward on voltage (typ.)
chip



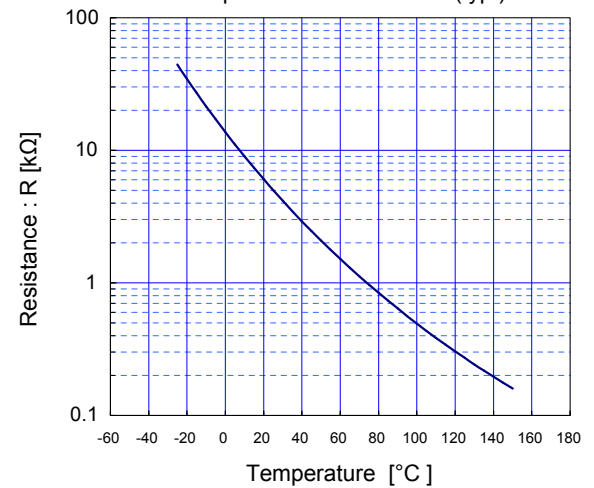
[Inverter]
Reverse recovery characteristics (typ.)
Vcc=600V, VGE=±15V, Rg=38Ω



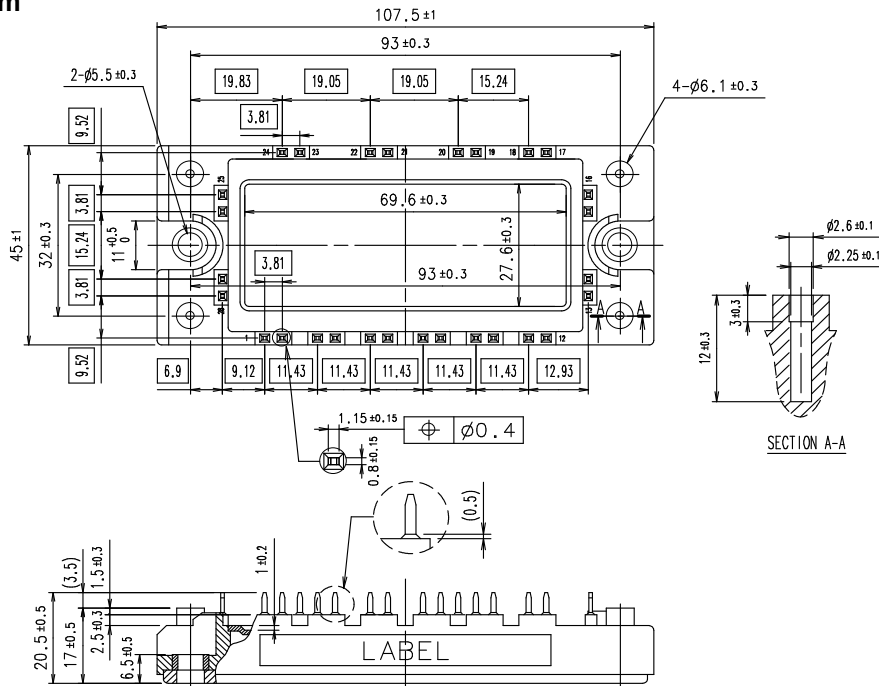
Transient thermal resistance (max.)



[Thermistor]
Temperature characteristic (typ.)



■ Outline Drawings, mm



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